General Description

The MAX13481E/MAX13482E/MAX13483E \pm 15kV ESDprotected USB-compliant transceivers interface lowvoltage ASICs with USB devices. The transceivers fully comply to USB 2.0 when operating at full-speed (12Mbps). The transceivers also operate with V_L as low as 1.6V, ensuring compatibility with low-voltage ASICs.

The MAX13481E/MAX13482E/MAX13483E feature a logic-selectable suspend mode that reduces current consumption. Integrated ± 15 kV ESD circuitry protects D+ and D- bus connections.

The MAX13481E/MAX13482E/MAX13483E operate over the extended -40°C to +85°C temperature range and are available in a 16-pin (3mm x 3mm) thin QFN package.

Applications

Cell Phones PDAs

Digital Still Cameras

Selector G	uide
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PART	ENUM INPUT	INTERNAL 1.5kΩ RESISTOR	V _{BUS} DETECTION
MAX13481EETE	~	_	—
MAX13482EETE	1	1	1
MAX13483EETE		_	1

Typical Operating Circuits appear at end of data sheet.



- Active-Low Enumeration Input Controls D+ Pullup Resistor (MAX13482E)
- Active-Low Enumeration Input Controls Internal Pullup Switch (MAX13481E)
- ±15kV ESD Protection on D+ and D-
- USB 2.0 Full-Speed Compliant Transceiver
- VBUS Detection (MAX13482E/MAX13483E)
- +1.60V to +3.6V V_L Allows Connection with Low-Voltage ASICs
- No Power-Supply Sequencing Required
- Pin Compatible with MIC2551A (MAX13481E)
- ♦ Pin Compatible with DP1680 (MAX13483E)
- ♦ Pin Compatible with DP1681 (MAX13481E)
- Pin Compatible with DP1682 (MAX13482E)

Ordering Information

		CODE
3mm X 3mm TQFN-EP*	ADF	T1633-4
3mm X 3mm TQFN-EP*	ADI	T1633-4
3mm X 3mm TQFN-EP*	ADJ	T1633-4
	3mm X 3mm TQFN-EP* 3mm X 3mm TQFN-EP* 3mm X 3mm TQFN-EP*	Bmm X 3mm TQFN-EP* ADF Bmm X 3mm TQFN-EP* ADI Bmm X 3mm TQFN-EP* ADJ

*EP = Exposed Paddle.

Pin Configurations



_____ Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND, unless	otherwise noted.)
V _{BUS} , V _L .	-0.3V to +7V
VTRM, VPUR, VPU	0.3V to (V _{BUS} + 0.3V)
Input Voltage (D+, D-)	0.3V to +7V
VM, VP, SUS, RCV, ENUM, BD, OE,	0.3V to $(V_L + 0.3V)$
Short-Circuit Current to V _{CC} or GND (D+	-, D-) ±150mA
Maximum Continuous Current (all other	pins)±15mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
16-Pin, 3mm x 3mm TQFN (derate 15.6mW	//°C above
+70°C)	1250mW
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{CC} = +4V to +5.5V, V_L = +1.6V to +3.6V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V_{CC} = +5V, V_L = +2.5V, T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	COND	ITIONS	MIN	ТҮР	МАХ	UNITS
SUPPLY INPUTS (VBUS, VTRM, V)						
V _{BUS} Input Range	VBUS			4.0		5.5	V
V _L Input Range	VL			1.6		3.6	V
Regulated Supply-Voltage Output	Vvtrm			3.0	3.3	3.6	V
Operating V _{CC} Supply Current	IVCC	Full-speed transmitting 12Mbps, $C_L = 50pF$ o	g/receiving at n D+ and D- (Note 2)			10	mA
Operating V _L Supply Current	IVL	Full-speed transmitting 12Mbps, $C_L = 15pFreeV_L = 2.5V (Note 2)$			2.5	mA	
Full-Speed Idle and SE0 Supply		Full-speed idle, V _{D+} >	→ 2.7V, V _{D-} < 0.3V		250	350	
Current	IVCC(IDLE)	SE0: $V_{D+} < 0.3V$, V_{D-}		250	350	μΑ	
Static VL Supply Current	IVL(STATIC)	Full-speed idle, SE0 o			5	μA	
Suspend Supply Current	IVCC(SUSP)	$VM = VP = open, \overline{ENU}$			35	μA	
Disabled-Mode Supply Current	IVCC(DIS)	$V_L = GND$ or open				20	μA
Sharing-Mode VL Supply Current	IVL(SHARING)	V _{BUS} = GND or open, VP = low or high, VM = high, ENUM = high			5	μΑ	
Disable-Mode Load Current on D+ and D-	IDX(DISABLE)	$V_L = GND$ or open, V_L	o_ = 0 or 5.5V			5	μA
Sharing-Mode Load Current on D+ and D-	IDX(SHARING)	V _{BUS} = GND or open,			20	μA	
	V _{TH_H}	Supply present		3.6			
USB Power-Supply Detection		Supply lost	$V_L \ge 1.7V$			0.8	V
	VIH_L	Supply lost	$V_L < 1.7V$			0.7	
USB Power-Supply Detection Hysteresis	VHYST				75		mV
V _L Supply-Voltage Detection Threshold	V _{TH(VL)}			0.85		V	

ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = +4V to +5.5V, V_L = +1.6V to +3.6V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V_{CC} = +5V, V_L = +2.5V, T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
ANALOG VOLTAGE OUTPUTS (V	PU, VPUR)		·				
Off-State Leakage	ILZ	$\overline{\text{ENUM}} = V_{L}$	-1		+1	μA	
VPU Switch Resistance		MAX13481E		10		Ω	
VPUR Pullup Resistance		MAX13482 (Note 3)	1.425		1.575	kΩ	
DIGITAL INPUTS/OUTPUTS (VP,VM, RCV, OE, ENUM, SUS, BD)							
Input-High Voltage	VIH	VP, VM, OE, ENUM, SUS	$0.7 \times V_{L}$			V	
Input-Low Voltage	VIL	VP, VM, OE, ENUM, SUS			$0.3 \times V_L$	V	
Output Voltage High	VOH	VP, VM, RCV, BD, I _{SOURCE} = 2mA	V _L - 0.4			V	
Output Voltage Low	VOL	VP, VM, RCV, BD, I _{SINK} = 2mA			0.4	V	
Input Leakage Current	ILKG		-1		+1	μA	
Input Capacitance		Measured from input to GND		10		рF	
ANALOG INPUT/OUTPUTS (D+, D) -)		·				
Differential Input Sensitivity	VDI	I(V _{D+} - V _{D-})I	200			mV	
Differential Common-Mode Voltage Range	VCM	Include V _{DI}	0.8		2.5	V	
Single-Ended Input-Low Voltage	VIL				0.8	V	
Single-Ended Input-High Voltage	VIH		2.0			V	
Hysteresis	V _{HYS}			250		mV	
Output Voltage Low	VOL	$R_L = 1.5k\Omega$ from D+ or D- to 3.6V			0.3	V	
Output Voltage High	VOH	$R_L = 15k\Omega$ to GND	2.8		3.6	V	
Off-State Leakage Current		Three-state driver	-1		+1	μA	
Transceiver Capacitance	CIND	D_ to GND		20		рF	
Driver Output Impedance	Rout		2		15	Ω	
ESD PROTECTION (D+, D-)							
Human Body Model				±15		kV	
IEC 61000-4-2 Contact Discharge				±8		kV	

TIMING CHARACTERISTICS

(V_{CC} = +4V to +5.5V, V_L = +1.6V to +3.6V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V_{CC} = +5V, V_L = +2.5V, T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS		
DRIVER CHARACTERISTICS (CL = 50pF)								
Rise Time D+/D-	t _{FR}	10% to 90% of IV _{OH} -V _{OL} I (Figures 1, 9)	4		20	ns		
Fall Time D+/D-	tFF	90% to 10% of IV _{OH} -V _{OL} I (Figures 1, 9)	4		20	ns		
Rise- and Fall-Time Matching transition from idle state (Figure 1) (Note 2)		90		110	%			

TIMING CHARACTERISTICS (continued)

(V_{CC} = +4V to +5.5V, V_L = +1.6V to +3.6V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V_{CC} = +5V, V_L = +2.5V, $T_A = +25^{\circ}C.)$ (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Output Signal Crossover Voltage	VCRS	(Figure 2) (Note 2)	1.3		2	V	
Driver Propagation Dalay	^t PLH_DRV	Low-to-high transition (Figure 2)			18	ns	
Driver Propagation Delay	^t PHL_DRV	High-to-low transition (Figure 2)			18	ns	
Driver Frederic Delay Time	^t PZH_DRV	Off-to-high transition (Figures 3, 10)			20	ns	
Driver-Enabled Delay Time	tpzl_drv	Off-to-low transition (Figures 3, 10)			20	ns	
Driver Dischlad Dalay	^t PHZ_DRV	High-to-off transition (Figures 3, 10)			20	ns	
Driver Disabled Delay	tplz_drv	Low-to-off transition (Figures 3, 10)			20	ns	
RECEIVER (C _L = 15pF)							
Differential Receiver	tplh_rcv	Low-to-high transition (Figures 4, 9)			20	ns	
Propagation Delay	tphl_rcv	High-to-low transition (Figures 4, 9)			20		
Single-Ended Receiver	^t PLH_SE	Low-to-high transition (Figures 4, 9)			12		
Propagation Delay	^t PHL_SE	High-to-low transition (Figures 4, 9)			12	ns	
Single-Ended Receiver Disable	tphz_se	High-to-off transition (Figure 5)			15		
Delay	tplz_se	Off-to-low transition (Figure 5)			15	ns	
Single-Ended Receiver Enable	tpzh_se	Off-to-high transition (Figure 5)			15		
Delay	tpzl_se	Off-to-low transition (Figure 5)			15	ris	

Note 1: Parameters are 100% production tested at +25°C, unless otherwise noted. Limits over temperature are guaranteed by design.

Note 2: Guaranteed by design, not production tested.

Note 3: Including external 27Ω series resistor.

(V_{BUS} = 5V, V_L = +3.3V, T_A = +25°C, unless otherwise noted.)

Typical Operating Characteristics



Typical Operating Characteristics (continued)

(V_{BUS} = 5V, V_L = +3.3V, T_A = +25°C, unless otherwise noted.)



MAX13481E/MAX13482E/MAX13483E



20ns/div





Pin Description

	PIN							
MAX13481E	MAX13482E	MAX13483E	NAME	FUNCTION				
8, 16	1, 8	1, 5, 8	N.C.	No Connection. Not internally connected.				
1	_	_	SP	Connect to V_L for Pin Compatibility to the MIC2551A or Leave Floating. Not internally connected.				
2	2	2	RCV	Differential Receiver Output. RCV responds to the differential input on D+ and D RCV asserts low when SUS = V_{L} .				
3	3	3	VP	Receiver Output/Driver Input. VP functions as a receiver output when $\overline{OE} = V_L$. VP duplicates D+ when receiving. VP functions as a driver input when $\overline{OE} = GND$.				

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MXXIM

_Pin Description (continued)

PIN NAM		NAME	FUNCTION	
4	4	4	VM	Receiver Output/Driver Input. VM functions as a receiver output when $\overline{OE} = V_L$. VM duplicates D- when receiving. VM functions as a driver input when $\overline{OE} = GND$.
5	5	_	ENUM	Active-Low Enumerator-Function-Selection Input. ENUM controls the pullup resistor or switch connection. See the ENUM section.
6	6	6	GND	Ground
7	7	7	SUS	Suspend Input. Drive SUS low for normal operation. Drive SUS high for low-power state. RCV asserts low and D+/ D- are high impedance in suspend mode. VP and VM remain active in suspend mode.
9	9	9	ŌĒ	Output Enable. Drive \overline{OE} to GND to enable the D+/D- transmitter outputs. Drive \overline{OE} to V _L to disable the transmitter outputs. \overline{OE} also controls the I/O directions of VP and VM (see Tables 3 and 4).
10	10	10	D-	USB Input/Output. For \overline{OE} = GND, D- functions as a USB output with VM providing the input signal. For \overline{OE} = V _L , D- functions as a USB input with VM functioning as a single-ended receiver output.
11	11	11	D+	USB Input/Output. For \overline{OE} = GND, D+ functions as a USB output with VP providing the input signal. For \overline{OE} = V _L , D+ functions as a USB input with VP functioning as a single-ended receiver output.
12	12	12	Vtrm	Regulated Output Voltage. V _{TRM} provides a 3.3V output derived from V _{BUS} . Bypass V _{TRM} to GND with a 1 μ F (min) low-ESR capacitor such as ceramic or plastic film types. V _{TRM} provides power to internal circuitry, the internal D+ pullup resistor, VPU and VPUR. Do not use V _{TRM} to power external circuitry.
13	_	_	VPU	Pullup Voltage. For $\overline{\text{ENUM}}$ = GND, VPU is pulled to an internal 3.3V voltage. Connect a 1.5k Ω resistor between D+ and VPU for full-speed operation. For $\overline{\text{ENUM}}$ = V _L , VPU is high impedance.
_	_	13	I.C.	Internally Connected. Leave open. Do not connect to external circuitry.
_	13	—	VPUR	Internal Pullup Resistor. VPUR is pulled to an internal 3.3V voltage through a 1.5k Ω resistor (ENUM = GND). Connect VPUR to D+ for full-speed operation. For ENUM = V _L , VPU is high impedance.
14	14	14	VBUS	USB-Side Power-Supply Input. Connect a +4V to +5.5V power supply to V _{BUS} . V _{BUS} supplies power to the internal regulator. Bypass V _{BUS} to GND with a 1 μ F ceramic capacitor. Connect V _{BUS} and V _{TRM} together when powering the MAX13481E/MAX13482E/MAX13483E with an external power supply.
15	15	15	VL	Digital Input/Output Connection Logic Supply. Connect a +1.6V to +3.6V supply to V _L . Bypass V _L to GND with a 0.1 μ F (min) low-ESR ceramic capacitor.
_	16	16	BD	USB Detector Output (Push/Pull). A high at BD signals to the ASIC that V_{BUS} is present.
EP	EP	EP	EP	Exposed Paddle. Connect EP to GND.

Detailed Description

The MAX13481E/MAX13482E/MAX13483E \pm 15kV ESDprotected USB-compliant transceivers convert singleended or differential logic-level signals to USB signals, and USB signals to single-ended or differential logic signals. These devices fully comply to USB 2.0 when operating at full-speed (12Mbps), and operate with V_L as low as 1.6V, ensuring compatibility with low-voltage ASICs. Integrated \pm 15kV ESD-circuitry protection protects D+ and D- bus connections.

The MAX13481E/MAX13483E require an external 1.5k Ω pullup resistor to V_{TRM} for full-speed operation. The MAX13481E requires an external 1.5k Ω pullup resistor and feature an active-low enumeration function that connects a +3.3V voltage at VPU. The MAX13482E features an active-low enumeration function that connects a 1.5k Ω pullup resistor at VPUR for full-speed operation. The MAX13482E/MAX13483E also provide a bus detect (BD) output that asserts high when V_{BUS} > 3.6V.

_Applications Information

Power-Supply Configurations

Normal Operating Mode

Connect V_L and V_{BUS} to system power supplies (Table 1). Connect V_L to a +1.6V to +3.6V supply. Connect V_{BUS} to a +4.0V to +5.5V supply or to the V_{BUS} connector.

Alternatively, these parts can derive power from a single Li+ cell. Connect the battery to V_{BUS}. VT_{RM} remains above +3.0V for V_{BUS} as low as +3.1V. Additionally, the devices can be powered by an external +3.3V \pm 10% voltage regulator. Connect V_{BUS} and V_{TRM} to an external +3.3V voltage regulator. V_{BUS} no longer consumes current to power the internal linear regulator in this configuration. The bus detect function (BD) on the MAX13482E and MAX13483E does not function when the device is powered this way.

Disable Mode

Connect V_{BUS} to a system power supply and leave V_L unconnected or connect to GND. D+ and D- enter a tristate mode and V_{BUS} (or V_{BUS} and V_{TRM}) consumes less than 20µA of supply current. D+ and D- withstand external signals up to +5.5V in disable mode (Table 2).

Table 1. Power-Supply Configuration

V _{BUS} (V)	VBUS (V) VTRM (V) VL (V) CONFIGURATION		NOTES	
+4.0 to +5.5	+3.0 to +3.6 output	+1.6 to +3.6	Normal mode	—
+4.0 to +5.5	+3.0 to +3.6 output	GND or floating	Disable mode	Table 2
GND or floating	High Z	+1.6 to +3.6	Sharing mode	Table 2
+3.1 to +4.5	+3.0 to +3.6 output	+1.6 to +3.6	Battery supply	
+3.0 to +3.6	+3.0 to +3.6 input	+1.6 to +3.6	Voltage regulator supply	—

Table 2. Disable-Mode and Sharing-Mode Connection

INPUTS/OUTPUTS	DISABLE MODE	SHARING MODE	
V _{BUS} / V _{TRM}	4V to 5.5V	Floating or connected to GND	
VL	Floating or connected to GND 1.6V to 3.6V inp		
D+ and D-	High impedance	High impedance	
VP and VM	Invalid*	For \overline{OE} = low, high impedance	
		For \overline{OE} = high, output logic high	
RCV	Invalid*	Undefined	
BD (MAX13482E/MAX13483E)	Invalid*	Low	

*High impedance or logic low



Sharing Mode

Connect V_L to a system power supply and leave V_{BUS} (or V_{BUS} and V_{TRM}) unconnected or connect to GND. D+ and D- enter a tri-state mode, allowing other circuitry to share the USB D+ and D- lines. V_L consumes less than 20 μ A of supply current. D+ and D- withstand external signals up to +5.5V in sharing mode (Table 2).

Device Control

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 \overline{OE} controls the direction of communication. Drive \overline{OE} low to transfer data from the logic side to the USB side. For \overline{OE} = low, VP and VM serve as differential driver inputs to the USB transmitter. Drive \overline{OE} high to transfer data from the USB side to the logic side. For \overline{OE} = high, VP and VM serve as single-ended receiver outputs from the USB inputs (D+ and D-). RCV serves as a differential receiver output, regardless of the state of \overline{OE} .

ENUM (MAX13481E/MAX13482E)

The MAX13481E/MAX13482E feature an active-low enumerate function that allows software control of the $1.5k\Omega$ pullup resistor and switch to D+ for full-speed operation.

For the MAX13481E, connect a $1.5k\Omega$ pullup resistor between D+ and VPU. The MAX13481E provides an internal switch that pulls VPU to a +3.3V voltage. Drive ENUM high to disconnect VPU from voltage. Drive ENUM low to connect VPU and the external pullup resistor to the +3.3V voltage.

The MAX13482E has an internal $1.5k\Omega$ resistor that connects at VPUR. Connect VPUR directly to D+. Drive ENUM high to disconnect the internal pullup resistor at VPUR. Drive ENUM low to connect the internal pullup resistor to VPUR.

SUS

The SUS state determines whether the MAX13481E/ MAX13482E/MAX13483E operate in normal mode or in suspend mode. Connect SUS to GND to enable normal operation. Drive SUS high to enable suspend mode. RCV asserts low and VP and VM remain active in suspend mode (Tables 3 and 4). In suspend mode, supply current is reduced.

Table 3. Transmit Truth Table $(\overline{OE} = 0)$

INPUTS		OUTPUTS		
VP	VM	D+	D-	
0	0	0	0	
0	1	0	1	
1	0	1	0	
1	1	1	1	

Table 4a. Receive Truth Table $(\overline{OE} = 1)$

INPUTS		OUTPUTS		
D+	D-	VP	VM	RCV
0	0	0	0	RCV*
0	1	0	1	0
1	0	1	0	1
1	1	1	1	Х

* = Last state

X = Undefined

Table 4b. Receive Truth Table $(\overline{OE} = 1, SUS = 1)$

INPUTS		OUTPUTS		
D+	D-	VP	VM	RCV
0	0	0	0	0
0	1	0	1	0
1	0	1	0	0
1	1	1	1	0

Transmitting Data to the USB

Data Transfer

To transmit data to the USB, drive \overline{OE} low. The MAX13481E/MAX13482E/MAX13483E transmit data to the USB differentially on D+ and D-. VP and VM serve as input signals to the differential driver and are also used to assert a single-ended zero (SE0) driver (see Table 3).

Receiving Data from the USB

To receive data from the USB, drive \overline{OE} high and SUS low. Differential data received by D+ and D- appears at RCV. Single-ended receivers on D+ and D- drive VP and VM, respectively.

RCV

RCV monitors D+ and D- when receiving data. RCV is a logic 1 for D+ high and D- low. RCV is a logic 0 for D+ low and D- high. RCV retains its last valid state when D+ and D- are both low (single-ended zero, or SE0).

ESD Protection

D+ and D- possess extra protection against static electricity to protect the devices up to ± 15 kV. The ESD structures withstand high ESD in all operating modes: normal operation, suspend mode, and powered down. D+ and D- provide protection to the following limits:

- ±15kV using the Human Body Model
- ±8kV using the Contact Discharge method specified in IEC 61000-4-2
- To protect V_{BUS} from ± 15 kV ESD, a 1µF or greater capacitor must be connected from V_{BUS} to GND.

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

Human Body Model

Figure 6 shows the Human Body Model and Figure 7 shows the current waveform generated when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which then discharges into the test device through a $1.5k\Omega$ resistor.

IEC 61000-4-2

The IEC 61000-4-2 standard covers ESD testing and performance of finished equipment. It does not specifically refer to integrated circuits. The major difference between tests done using the Human Body Model and IEC 61000-4-2 is a higher peak current in IEC 61000-4-2, due to lower series resistance. Hence, the ESD with-



VTRM

An internal linear regulator generates the V_{TRM} voltage (+3.3V, typ). V_{TRM} derives power from V_{BUS} (see the *Power-Supply Configurations* section). V_{TRM} powers the internal portions of the USB circuitry and provides the pullup voltage for the MAX13481E/MAX13482E. Bypass V_{TRM} to GND with a 1 μ F ceramic capacitor as close to the device as possible. Do not use V_{TRM} to provide power to any other external circuitry.

D+ and D-

D+ and D- serve as bidirectional bus connections and are ESD-protected to ± 15 kV (Human Body Model). For \overline{OE} = low, D+ and D- serve as transmitter outputs. For \overline{OE} = high, D+ and D- serve as receiver inputs.

BD (MAX13482E/MAX13483E)

The push-pull bus detect (BD) output monitors V_{BUS} and asserts high if V_{BUS} is greater than V_{TH_H} . BD asserts low if V_{BUS} is less than V_{TH_L} , and the MAX13482E/MAX13483E enter sharing mode (Table 2).

VBUS

For most applications, V_{BUS} connects to the V_{BUS} terminal on the USB connector (see the *Power-Supply Configurations* section). V_{BUS} can also connect to an external supply. Drive V_{BUS} low to enable sharing mode. Bypass V_{BUS} to GND with a 1 μ F ceramic capacitor as close to the device as possible.

External Components

External Capacitors

The MAX13481E/MAX13482E/MAX13483E require three external capacitors for proper operation. Bypass V_L to GND with a 0.1 μ F ceramic capacitor. Bypass V_{BUS} to GND with a 1 μ F ceramic capacitor. Bypass V_{TRM} to GND with a 1 μ F (min) ceramic capacitor. Install all capacitors as close to the device as possible.

External Resistor

Proper USB operation requires two external resistors, each 27 Ω ±1%. Install one resistor in series between D+ of the MAX13481E/MAX13482E/MAX13483E and D+ on the USB connector. Install the other resistor in series between D- of the MAX13481E/MAX13482E/MAX13483E and D- on the USB connector (see the *Typical Operating Circuits*). The MAX13483E requires an external 1.5k Ω pullup resistor between V_{TRM} and D+ for full-speed operation. The MAX13481E requires an external 1.5k Ω pullup resistor between VPU and D+ for full-speed operation. The MAX13482E does not require an external pullup resistor but VPUR must be connected to D+ for full-speed operation.

Timing Diagrams



Figure 1. Rise and Fall Times



Figure 2. Timing of VP and VM to D+ and D-

stand voltage measured to IEC 61000-4-2 generally is lower than that measured using the Human Body Model. Figure 8 shows the IEC 61000-4-2 model. The Contact Discharge method connects the probe to the device before the probe is charged.

Machine Model

The Machine Model for ESD tests all connections using a 200pF storage capacitor and zero discharge resis-



Figure 3. Driver's Enable and Disable Timing

tance. Its objective is to emulate the stress caused by contact that occurs with handling and assembly during manufacturing. All pins require this protection during manufacturing, not just inputs and outputs. After PC board assembly, the Machine Model is less relevant to I/O ports.



Figure 4. D+/D- Timing to VP, VM, and RCV





Timing Diagrams (continued)



Figure 6. Human Body ESD Test Model



Figure 7. Human Body Model Current Waveform



Figure 8. IEC 61000-4-2 ESD Test Model



Test Circuits



Figure 9. Transmitter and Receiver Propagation Delay



Figure 10. Driver's Enable and Disable Timing





_Functional Diagrams (continued)



Functional Diagrams (continued)



_Typical Operating Circuits





_Chip Information

PROCESS: BICMOS

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to **www.maxim-ic.com/packages**.)



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